

### High voltage fast-switching NPN power transistor

#### **Features**

- High voltage capability
- Minimum lot-to-lot spread for reliable operation
- Very high switching speed

#### **Applications**

- Electronic ballast for fluorescent lighting
- Flyback and forward single transistor low power converters

#### **Description**

The device is manufactured using high voltage multi-epitaxial planar technology for high switching speeds and medium voltage capability.

It uses a cellular emitter structure with planar edge termination to enhance switching speeds while maintaining the wide RBSOA.

The device is designed for use in lighting applications and low cost switch-mode power supplies.

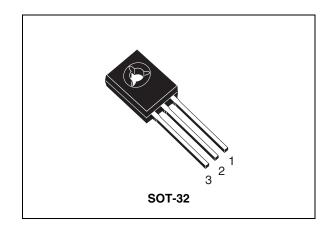


Figure 1. Internal schematic diagram

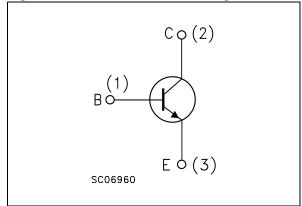


Table 1. Device summary

Order codes	Marking	Package	Packaging
STT13005	T13005	SOT-32	Tube
STT13005-K	T13005	SOT-32	Bag

Electrical ratings STT13005

# 1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V <sub>CES</sub>	Collector-emitter voltage (V <sub>BE</sub> = 0)	700	V
V <sub>CEO</sub>	Collector-emitter voltage (I <sub>B</sub> = 0)	400	V
V <sub>EBO</sub>	Emitter-base voltage (I <sub>C</sub> = 0)	9	V
I <sub>C</sub>	Collector current	2	Α
I <sub>CM</sub>	Collector peak current (t <sub>P</sub> < 5 ms)	4	Α
I <sub>B</sub>	Base current	1	Α
I <sub>BM</sub>	Base peak current (t <sub>P</sub> < 5 ms)	2	Α
P <sub>tot</sub>	Total dissipation at $T_c = 25$ °C	45	W
T <sub>stg</sub>	Storage temperature	-65 to 150	°C
T <sub>J</sub>	Max. operating junction temperature	150	°C

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R <sub>thJC</sub>	Thermal resistance junction-case Max	2.8	°C/W

## 2 Electrical characteristics

 $T_{case}$  = 25 °C unless otherwise specified.

Table 4. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I <sub>CES</sub>	Collector cut-off current (V <sub>BE</sub> = 0)	V <sub>CE</sub> = 700 V V <sub>CE</sub> = 700 V T <sub>C</sub> = 125 °C			100 500	μ <b>Α</b> μ <b>Α</b>
I <sub>CEO</sub>	Collector cut-off current (I <sub>B</sub> = 0)	V <sub>CE</sub> = 400 V			250	μΑ
V <sub>EBO</sub>	Emitter-base voltage $(I_C = 0)$	I <sub>E</sub> = 10 mA	9			V
V <sub>CEO(sus)</sub> (1)	Collector-emitter sustaining voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = 10 mA	400			V
V <sub>CE(sat)</sub> (1)	Collector-emitter saturation voltage	$\begin{split} I_{C} &= 0.5 \text{ A} & I_{B} = 125 \text{ mA} \\ I_{C} &= 0.8 \text{ A} & I_{B} = 0.2 \text{ A} \\ I_{C} &= 1.6 \text{ A} & I_{B} = 0.4 \text{ A} \end{split}$			0.5 1 1.5	V V V
V <sub>BE(sat)</sub> (1)	Base-emitter saturation voltage	$\begin{split} I_{C} &= 0.5 \text{ A} & I_{B} = 125 \text{ mA} \\ I_{C} &= 0.8 \text{ A} & I_{B} = 0.2 \text{ A} \\ I_{C} &= 1.6 \text{ A} & I_{B} = 0.4 \text{ A} \end{split}$			1 1.3 1.5	V V V
h <sub>FE</sub> <sup>(1)</sup>	DC current gain	$I_C = 0.5 \text{ A}$ $V_{CE} = 5 \text{ V}$ $I_C = 2 \text{ A}$ $V_{CE} = 5 \text{ V}$	10 8		50	
t <sub>r</sub> t <sub>s</sub>	Resistive load Rise time Storage time Fall time	$I_C = 1 \text{ A}$ $V_{CC} = 125 \text{ V}$ $I_{B1} = -I_{B2} = 0.2 \text{ A}$		0.4 3.2 0.25	0.7 4.5 0.4	µs µs µs
t <sub>s</sub>	Inductive load Storage time Fall time	$\begin{split} I_{C} &= 1 \text{ A} & I_{B1} = 0.2 \text{ A} \\ V_{BE(off)} &= -5 \text{ V} & L = 50 \text{ mH} \\ V_{Clamp} &= 300 \text{ V} \end{split}$		0.8 0.16		μs μs

<sup>1.</sup> Pulse test: pulse duration  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2 %

Electrical characteristics STT13005

#### 2.1 Electrical characteristics (curves)

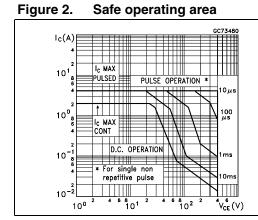


Figure 3. Derating curve

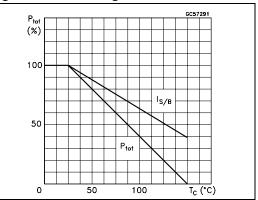
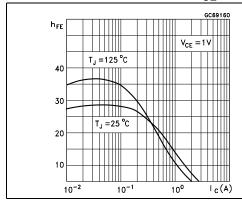


Figure 4. DC current gain (V<sub>CE</sub> = 1 V) Figure 5. DC

re 5. DC current gain (V<sub>CE</sub> = 5 V)



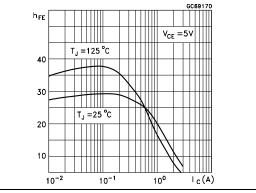
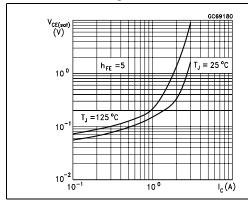


Figure 6. Collector-emitter saturation voltage

Figure 7. Base-emitter saturation voltage



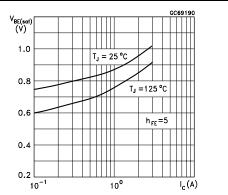
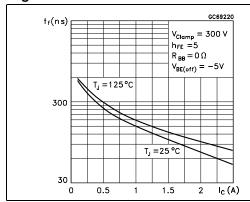


Figure 8. Inductive load fall time

Figure 9. Inductive load storage time



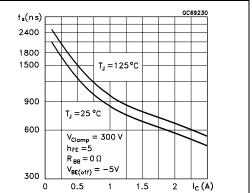
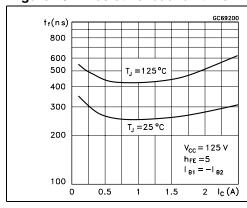


Figure 10. Resistive load fall time

Figure 11. Resistive load storage time



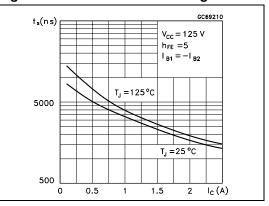
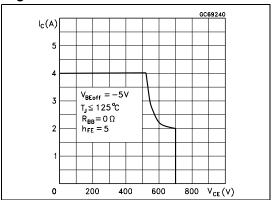


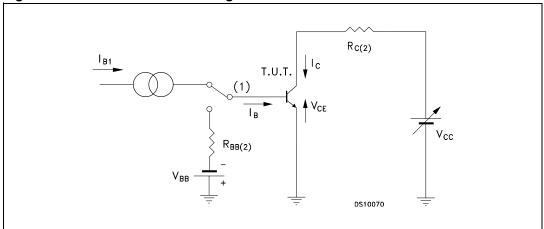
Figure 12. Reverse biased SOA



Electrical characteristics STT13005

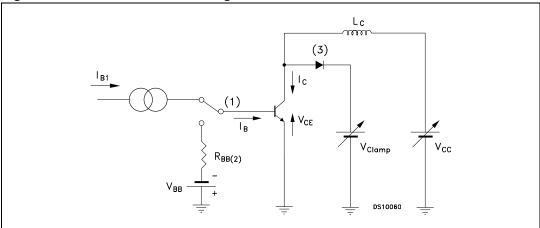
#### 2.2 Test circuits

Figure 13. Resistive load switching test circuit



- 1. Fast electronic switch
- 2. Non-inductive resistor

Figure 14. Inductive load switching test circuit

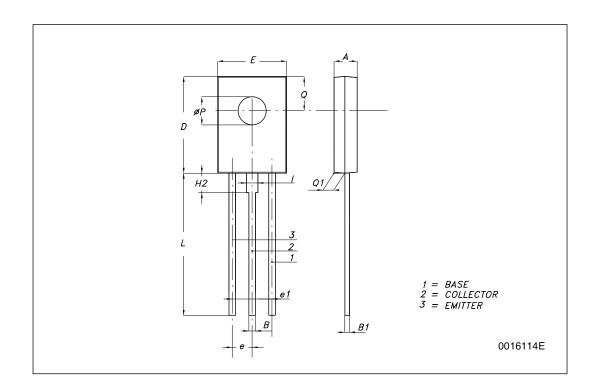


- 1. Fast electronic switch
- 2. Non-inductive resistor
- 3. Fast recovery rectifier

# 3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: <a href="https://www.st.com">www.st.com</a>. ECOPACK<sup>®</sup> is an ST trademark.

DIM.		mm.	
	MIN.	TYP	MAX.
Α	2.4		2.9
В	0.64		0.88
B1	0.39		0.63
D	10.5		11.05
E	7.4		7.8
е	2.04	2.29	2.54
e1	4.07	4.58	5.08
L	15.3		16
Р	2.9		3.2
Q		3.8	
Q1	1		1.52
H2		2.15	
I		1.27	



STT13005 Revision history

# 4 Revision history

Table 5. Document revision history

Date	Revision	Changes
29-May-2007	1	Initial release
10-Jul-2008	2	Updated: V <sub>CEO(sus)</sub> condition in <i>Table 4 on page 3</i> , SOT-32 mechanical data
03-Nov-2009	3	Added order code STT13005-K Table 1 on page 1

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